

# GDU 90 20722

# **GATE DRIVE UNIT**

This data sheet should be used in conjuction with the publication entitled GDU9X-XXXXX Series, Gate Drive Unit.

APPLICATIONS KEY PARAMETERS

■ Used with Gate Turn-Off Thyristors in high current switching applications

 $\begin{array}{ll} I_{\text{FGM}} & \text{40A} \\ I_{\text{G(ON)}} & \text{10A} \\ \text{d}I_{\text{GQ}}/\text{dt} & \text{50A/}\mu\text{s} \end{array}$ 

### **CONDITIONS - (UNLESS STATED OTHERWISE)**

V <sub>1</sub> = +5V	V <sub>2</sub> = +15V		V <sub>3</sub> = -15V		
Test circuit GTO		DG858BW			
GDU connection to GTO		500mm CO - AX cable type RC5327230 (2 cables in parallel)			
Test circuit emitter and gate drive emitter		Honeywell sweetspot HFE 4020 - 013			
Test circuit emitter current		30mA			
Test circuit receiver and gate drive receiver		Honeywell sweetspot HFD 3029 - 002			

#### **ELECTRICAL CHARACTERISTICS**

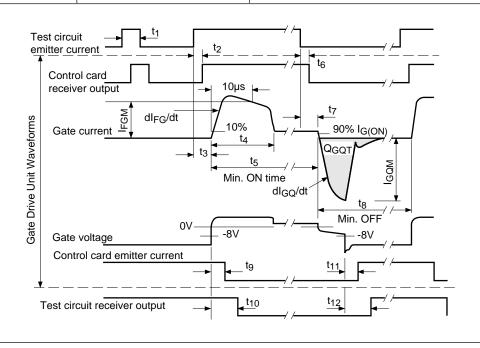
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
I <sub>V1</sub>	+5V PSU current	500Hz, 50% duty cycle	-	-	5.5	А
I <sub>V2</sub>	+15V PSU current	500Hz	-	-	0.70	Α
I <sub>V3</sub>	-15V PSU current	500Hz, I <sub>T</sub> = 3000A GTO T <sub>j</sub> = 125°C	-	-	12	Α
V <sub>1(Min)</sub>	+5V PSU minimum	-	3.8	-	-	V
V <sub>2(Min)</sub>	+15V PSU minimum	-	14.0	-	-	V
V <sub>3(Min)</sub>	-15V PSU minimum	-	14.0	-	-	V
I <sub>FGM</sub>	Peak forward gate current	-	40	-	-	А
I <sub>G(ON)</sub>	On-state gate current	-	-	10	-	А
dl <sub>FG</sub> /dt	Rate of rise of positive gate current	Measured 10 - 75% I <sub>FGM</sub>	-	40	-	A/μs
dl <sub>GQ</sub> /dt	Rate of rise of negative gate current	I <sub>T</sub> = 3000A, 90% I <sub>G(ON)</sub> - 50% I <sub>GQM</sub>	-	50	-	A/μs

#### **TIMING CHARACTERISTICS**

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
t,*†	No response pulse width of input signal	Adjustable by R81 + R82	2	-	3	μs
t <sub>2</sub>	Delay time emitter current to receiver o/p	-	0.4	-	0.8	μs
t <sub>3</sub> *†	Turn-on delay emitter current to 10% I <sub>FGM</sub>	-	5.2	-	6.2	μs
t <sub>4</sub>	I <sub>FGM</sub> pulse width	-	-	25	-	μs
t <sub>5</sub> *	Minimum on time 10% I <sub>FGM</sub> to 90% I <sub>G(ON)</sub>	Adjustable by R37	80	-	110	μs
t <sub>6</sub>	Receiver storage time	-	0.5	-	0.9	μs
t <sub>7</sub>	Turn-off delay. Emitter current to 90% I <sub>G(ON)</sub>	-	1.5	-	2.3	μs
t <sub>8</sub> *	Minimum off time 90% I <sub>G(ON)</sub> to 10% I <sub>FGM</sub>	Adjustable by R38	80	-	110	μs
t <sub>9</sub>	Delay time Gate volts to o/p emitter current	-	-	0.1	-	μs
t <sub>10</sub>	Turn-off delay Gate volts to test receiver o/p	-	-	0.7	-	μs
t <sub>11</sub>	Storage time Gate volts to o/p emitter current	Measured at low I <sub>GQM</sub>	-	0.11	-	μs
t <sub>12</sub>	Turn-on delay Gate volts to test receiver o/p	Measured at low I <sub>GQM</sub>	-	0.81	-	μs

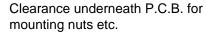
<sup>\*</sup> t<sub>1</sub>,t<sub>3</sub>,t<sub>5</sub>,t<sub>8</sub> are factory settings.

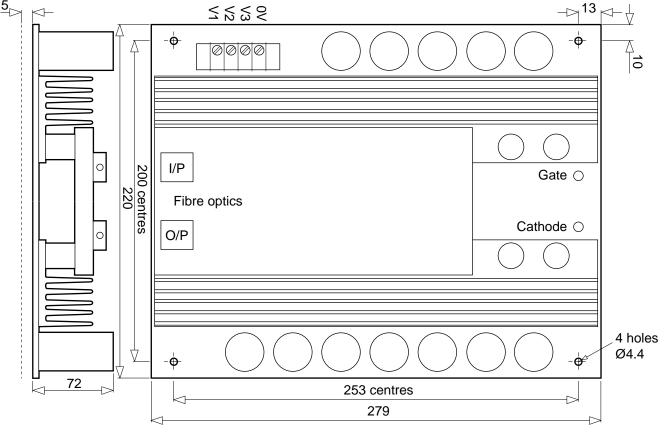
<sup>1.</sup> Varies with  $\rm I_{\rm GQM}$  due to gate lead impedance.



<sup>†</sup> Adjustment of t<sub>1</sub> alters t<sub>3</sub>.

## OUTLINE





Weight: 2.12Kg

All dimensions in mm, unless stated otherwise. DO NOT SCALE.



### HEADQUARTERS OPERATIONS **GEC PLESSEY SEMICONDUCTORS**

Cheney Manor, Swindon, Wiltshire, SN2 2QW, United Kingdom. Tel: + 44 (0)1793 518000

Fax: + 44 (0)1793 518411

#### **GEC PLESSEY SEMICONDUCTORS**

P.O. Box 660017 1500 Green Hills Road, Scotts Valley, California 95067-0017, United States of America. Tel: + 1 (408) 438 2900 Fax: + 1 (408) 438 5576

#### POWER PRODUCT CUSTOMER SERVICE CENTRES

- FRANCE. 2 rue Henri-Bergson, 92665 Asnieres Cedex. Tel: + 33 1 40 80 54 00. Fax: + 33 1 40 80 55 87.
- GERMANY, Ungererstrasse 129, 80505 München. Tel: + 49 (0)89 36 09 060. Fax: + 49 (0)89 36 09 06 55.
- NORTH AMERICA. At Dedham Place, Suite 125, 3 Allied Drive, Dedham. MA 02026. Tel: + 1 617 251 0126. Fax: + 1 617 251 0106.
- UNITED KINGDOM. Doddington Road, Lincoln. LN6 3LF. Tel: + 44 (0)1522 500500. Fax: + 44 (0)1522 500550.

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